PNP/NPN Epitaxial Planar Silicon Transistors



2SB1296/2SD1936

AF Amplifier Applications

Applications

· AF power amplifier, medium-speed switching, small-sized motor drivers.

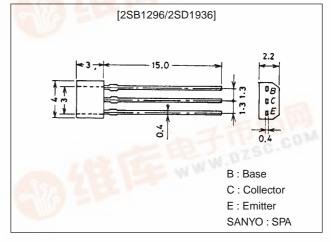
Features

- · Large current capacity.
- · Low collector to emitter saturation voltage.
- · Wide ASO.

Package Dimensions

unit:mm

2033



(): 2SB1296

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Symbol Conditions		Unit	
Collector-to-Base Voltage	V _{CBO}		(-)15	V	
Collector-to-Emitter Voltage	V _{CEO}		(-)15	V	
Emitter-to-Base Voltage	V _{EBO}	pall.	(-)5	V	
Collector Current	IC		(-)0.8	Α	
Collector Current (Pulse)	ICP	4 Lib (1922 12)	(–)3	А	
Collector Dissipation	PC	AND AFTER V	300	mW	
Junction Temperature	Tj	MISSI LEVEL	150	°C	
Storage Temperature	Tstg		-55 to +150	°C	

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Unit		
Falantetel		Conditions	min	typ	max	Offic
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)12V, I _E =0			(-)100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)100	nA
	h _{FE} 1	$V_{CE}=(-)2V, I_{C}=(-)50mA$	140*		(560)*	11:
DC Current Gain		4.0	_		800*	Ago.
	h _{FE} 2	V _{CE} =(-)2V, I _C =(-)800mA	80		60.	2.00

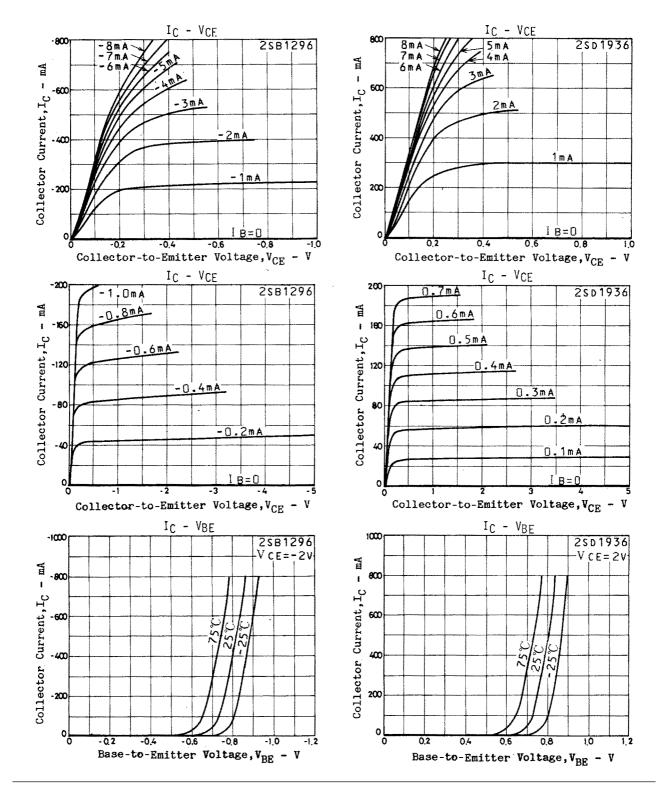
 \ast : The 2SB1296/2SD1936 are classified by 50mA h_{FE} as follows :

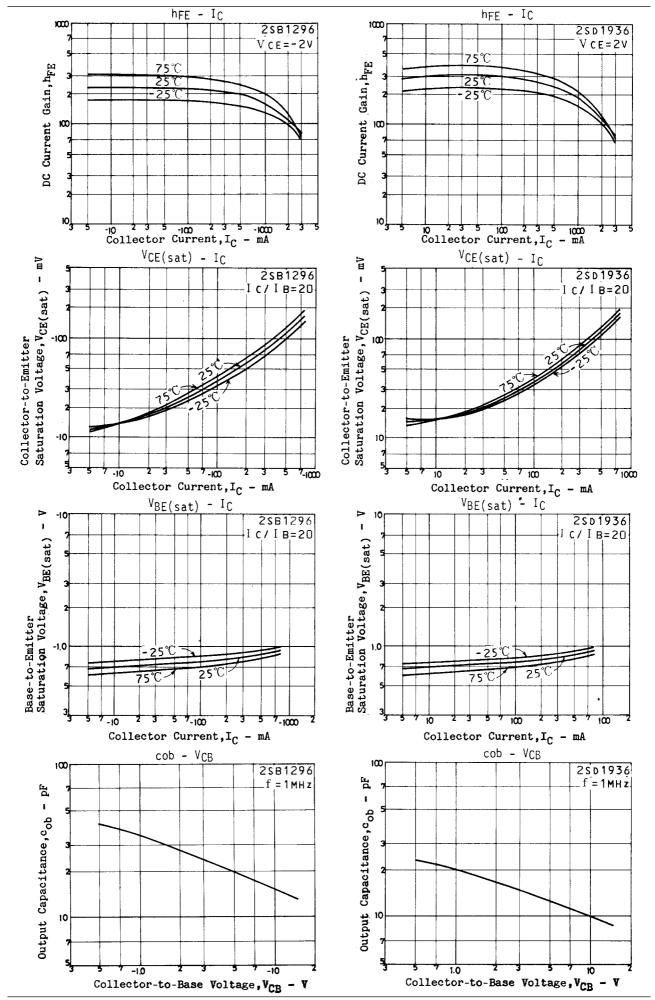
2SB1296	140	S	280	200	Т	400	280	U	560			
2SB1936	140	S	280	200	Т	400	280	U	560	400	V	800

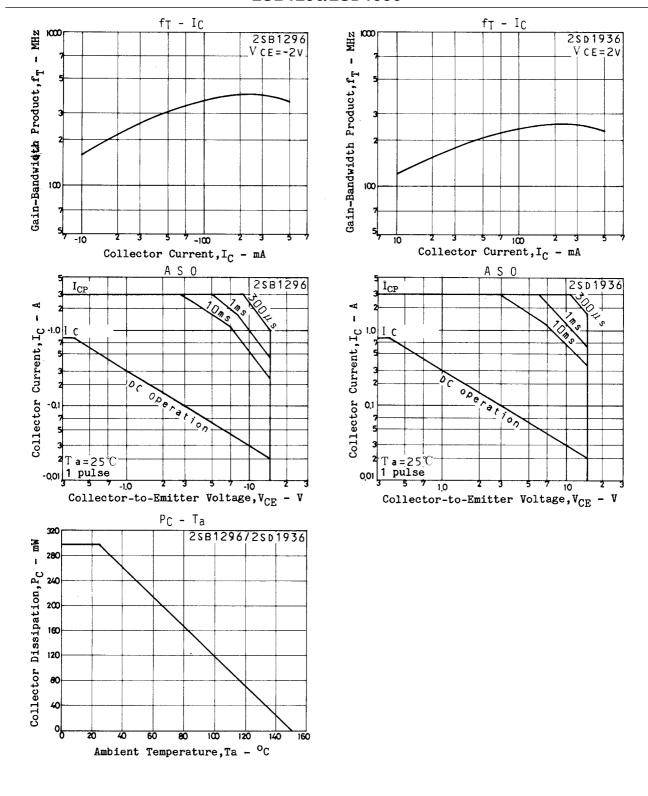
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TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

Parameter	Cumhal	Conditions		Ratings			
Farameter	Symbol	Conditions		typ	max	Unit	
Gain-Bandwidth Product	fT	V _{CE} =(-)2V, I _C =(-)50mA		(300)		MHz	
				200		MHz	
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(15)		pF	
				10		pF	
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} 1	I _C =(-)5mA, I _B =(-)0.5mA		(–)10	(–)25	mV	
	V _{CE(sat)} 2	I _C =(-)400mA, I _B =(-)20mA		(-)100	(–)200	mV	
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)400mA, I _B =(-)20mA		(–)0.9	(-)1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10μA, I _E =0	(–)15			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(–)1mA, R _{BE} =∞	(–)15			V	
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(-)10μΑ, I _C =0	(-)5			V	







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